

Supporting Information for

***In-situ* Annealed $\text{Ti}_3\text{C}_2\text{T}_x$ MXene Based All-Solid-State Flexible Zn-Ion Hybrid Micro Supercapacitor Array with Enhanced Stability**

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Supplementary Tables and Figures

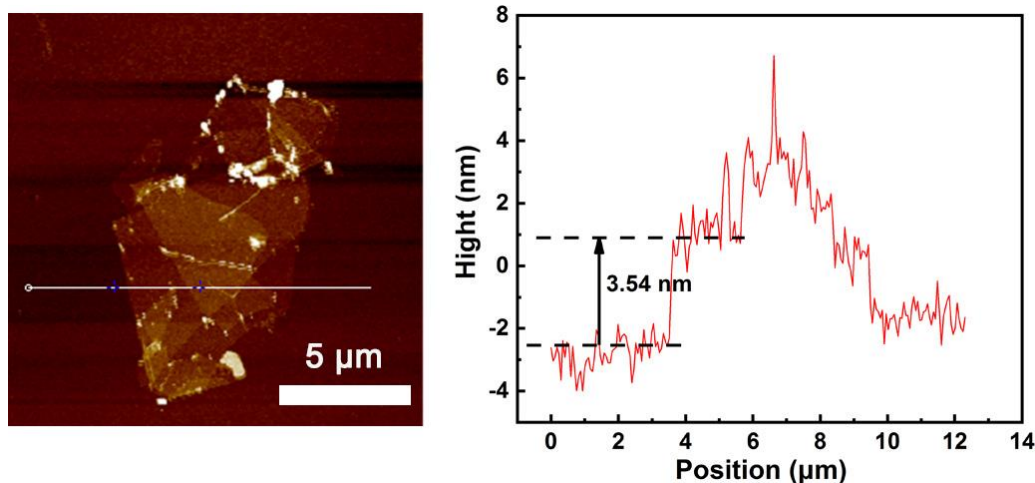


Fig. S1 AFM images of the $\text{Ti}_3\text{C}_2\text{T}_x$ flakes

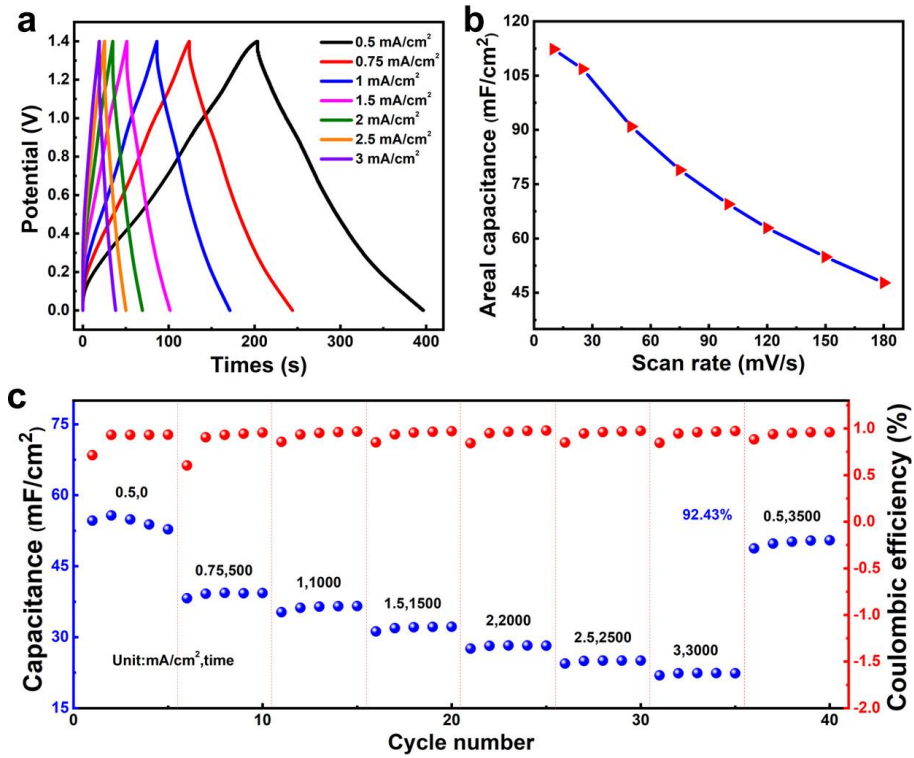


Fig. S2 **a** Galvanostatic charge-discharge curves. **b** areal capacitance and **c** rate stability of the fabricated MSCs without anneal

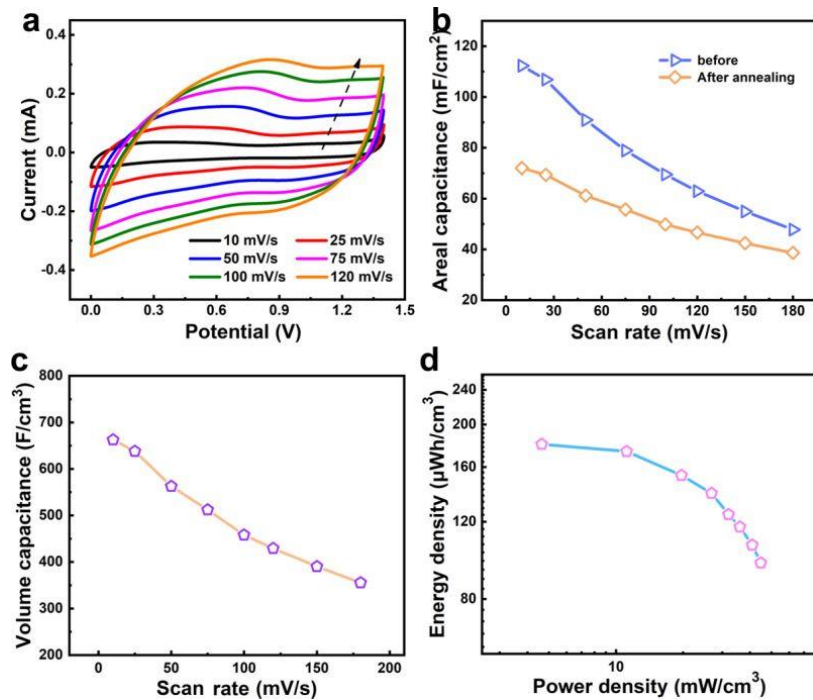


Fig. S3 **a** CV curves, **b** compared areal capacitance, **c** volume capacitance and **d** range plot of *in-situ* annealed Zn-ion MSCs

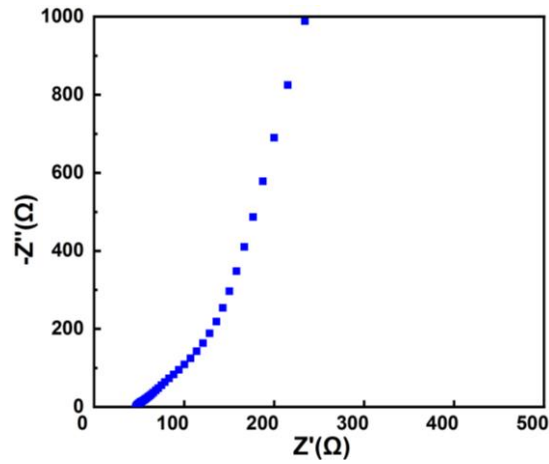


Fig. S4 Nyquist impedance of the $\text{Ti}_3\text{C}_2\text{T}_x$ based concentric circular Zn-ion MSC after annealing treatment

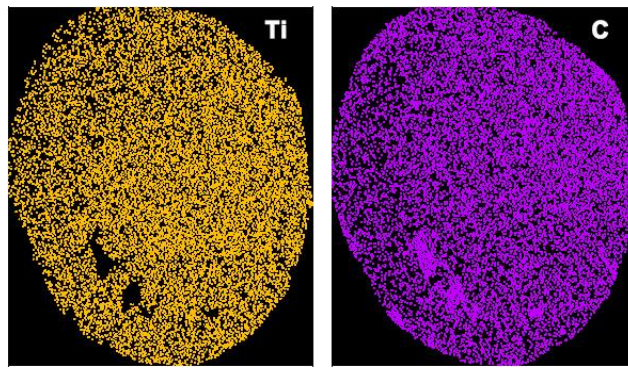


Fig. S5 Ti and C element dispersion in the $\text{Ti}_3\text{C}_2\text{T}_x$ cathode, corresponding to Fig. 4b

Calculation:

Areal and volumetric capacitances can be calculated by the equations:

$$C_A = \frac{\int_0^v I \, dv}{SV_A}$$

Where C_A represents the specific areal/volume capacitance, I is the current, S stands for the scan rate, V is the potential in the CV curve, A is the areal or volume of the devices.

The energy density and power density:

$$E = C_A \times \Delta V^2 / 7200$$

$$P = E \times 3600 / \Delta t$$

Where E represents the energy density, P is the power density, and Δt is the total discharge time.